

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:	Jack H. Yuan et al.		
Title:	Non-Volatile Memory Cell Array Having Discontinuous Source and Drain Diffusions Contacted by Continuous Bit Line Conductors and Methods of Forming		
Application No.:	Unassigned	Filing Date:	Herewith
Examiner:	Unassigned	Group Art Unit:	Unassigned
Docket No.:	SNDK.217US2	Conf. No.:	Unassigned

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Mail Stop Patent Application  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**PRELIMINARY AMENDMENT**

Dear Sir:

Please amend the above-identified continuation application with which this Preliminary Amendment is being filed, as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims, which begins on page 3 of this paper.

**Remarks** begin on page 4 of this paper.